NSN 5961-00-166-4021

Demilitarization:

No Fiig: A110a0



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-00-166-4021 **Inclosure Material:** Metal **Overall Length:** 6.500 inches **Overall Height:** 0.750 inches **Overall Width:** 0.750 inches **Mounting Facility Quantity: Mounting Method:** Threaded hole **Features Provided:** Hermetically sealed case **Thread Size:** 0.138 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40000.0 reverse voltage, peak and 65.0 forward voltage, peak **Current Rating Per Characteristic:** 25.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Test Data Document:** 10001-2836190 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Thread Series Designator:** Unc **Terminal Type And Quantity:** 2 turret Shelf Life: N/a **Unit Of Measure:**